

NAND01GW3B2BZA6E

NAND01GW3B2BZA6E Information



For Reference Only

Part NumberNAND01GW3B2BZA6EManufacturerMicron Technology Inc.CategoryIntegrated Circuits (ICs)

Memory

Description IC FLASH 1GBIT 30NS 63VFBGA

Package 63-TFBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NAND01GW3B2BZA6E Specifications

Manufacturer Part Number	NAND01GW3B2BZA6E
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	63-TFBGA
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	1Gb (128M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	30ns
Access Time	30ns
Voltage - Supply	2.7 V ~ 3.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	63-TFBGA
Supplier Device Package	63-VFBGA (9x11)
	Report errors?

NAND01GW3B2BZA6E Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NAND01GW3B2BZA6E Payment Methods





















NAND01GW3B2BZA6E Shipping Methods













If you have any question about NAND01GW3B2BZA6E, please do not hesitate to contact us!

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